

B 2163

B.E./B.Tech. DEGREE EXAMINATION, MAY/JUNE 2007.

Third Semester

Electronics and Communication Engineering

EC 234 — ELECTRONIC CIRCUIT — I

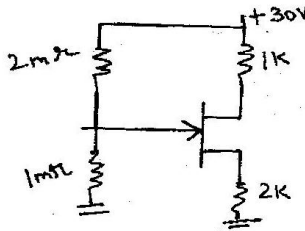
Time : Three hours

Maximum : 100 marks

Answer ALL questions.

PART A — (10 × 2 = 20 marks)

1. Determine the operating point ' θ ' and locate it on the dc load line for the circuit shown.



2. Briefly explain with circuit diagram diode compensation technique for I_{co} in BJT.
3. Derive the input impedance of an emitter follower with equivalent circuit.
4. Give the drain current expressions in Triode region and in saturation region of MOSFET.
5. With class C power amplifier circuit define class C operation.
6. A power device is mounted on a heat sink with $\theta_{c-s} = 1^\circ \text{C/w}$, $\theta_{j-c} = 7.5^\circ \text{C/w}$ and $\theta_{c-a} = 5^\circ \text{C/w}$. Find the maximum power dissipation of the device when $T_{jmax} = 175^\circ \text{C}$.
7. Why gain drops at low and high frequencies?

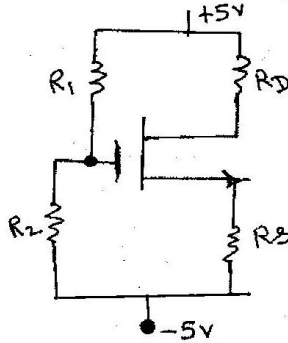
8. Briefly explain dominant pole high frequency compensation method used in amplifiers.
9. SMPS has an output of 10 V for input fluctuations of 15 V to 25 V. Find the variation of duty cycle of pulse width modulator of the power supply.
10. Draw a simple circuit to control ac signal power using SCR.

PART B — (5 × 16 = 80 marks)

11. (a) Determine the stability factor for variations of I_{CO} , h_{fe} and V_{BE} of a self Bias circuit used in BJT amplifiers.

Or

- (b) (i) Explain constant current biasing used in JFET amplifiers. (6)
- (ii) Design a MOSFET biasing circuit shown with following data. (10)



$$I_{DQ} = .25 \text{ mA}$$

$$V_{DSQ} = 4 \text{ V}$$

$$V_{RS} = 1 \text{ V}$$

$$\text{Current through biasing resistors} = 20 \text{ } \mu\text{A}$$

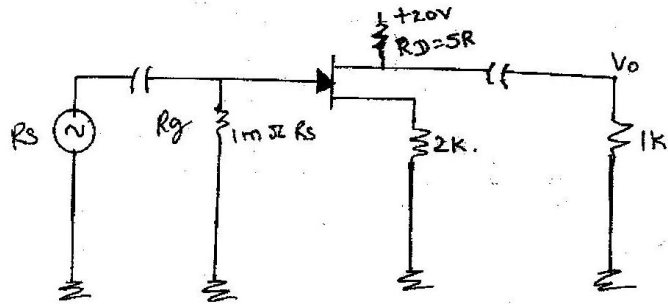
$$V_{th} = 1.2 \text{ V}$$

$$W/L = 4 \text{ and } K_n' = \mu_n C_{ox} = 80 \text{ } \mu\text{A/V}^2.$$

12. (a) Draw a differential amplifier circuit and its small signal equivalent circuit. Derive its differential gain, common mode gain and CMRR. Suggest a method to improve the CMRR.

Or

- (b) (i) Draw the equivalent circuit of the amplifier shown and find its voltage, gain R_{in} and R_o . (10)



Assume $r_d = 40\text{ k}$ and $g_m = 5\text{ mA/V}$

- (ii) Draw a Darlington amplifier and its equivalent circuit. Mention its special features. (6)
13. (a) (i) Explain the working of class B complementary and symmetry power amplifier. Derive its efficiency. How its cross-over distortion can be removed. (12)
- (ii) Calculate the efficiency of a class B power amplifier with ac peak to peak voltage at output is 5 V. Assume $V_{cc} = 5\text{ V}$. (4)

Or

- (b) (i) Describe the function of Class A power amplifier with circuit. Derive its efficiency. Also suggest a method to improve its efficiency. (10)
- (ii) What is thermal runaway? What are design aspects that have to be taken care of while designing power amplifier to have thermal stability? (6)
14. (a) Explain FWR with π filter and derive the ripple factor of the FWR with π filter.

Or

- (b) Describe the regulation of the output voltage with respect to input voltage and load variations of a linear voltage regulator.